## NSN 5962-01-420-9495

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View Online at https://aerobasegroup.com/nsn/5962-01-420-9495 **Body Length:** 0.358 inches **Body Width:** 0.358 inches **Body Height:** 0.075 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Pacer dawn **Features Provided:** Electrostatic sensitive and programmed and monolithic **Inclosure Configuration:** Leaded chip carrier **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Criticality Code Justification:** Cbbl **Case Outline Source And Designator:** C-2a mil-m-38510 **Terminal Surface Treatment:** Solder **Product Name:** Microcircuit, programmed (pal c16r4-20) **Voltage Rating And Type Per Characteristic:** 5.0 volts power source **Time Rating Per Chacteristic:** 20.00 nanoseconds input to output access **Memory Device Type:** Pal **Special Features:** Altered item, altered from p/n 5962-8871312xa, cage 67268, program p/n 7554025p14, microcircuits, digital, cmos programmable logic array, monolithic silicon **Test Data Document:** 96906-mil-std883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 

N/a

20 gullwing **Shelf Life:** 

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In	18	<i>(</i> )+	МЛО	201	ure:

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Demilitarization:

No

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